WNSC16650CW

Silicon Carbide Diode

Rev.01 - 07 September 2020 Product data sheet

1. General description

Dual Silicon Carbide Schottky diode in a TO247-3L plastic package, designed for high frequency switched-mode power supplies.

RoHS Halogen-Free Lead-Free

2. Features and benefits

- Highly stable switching performance
- High forward surge capability I_{FSM}
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

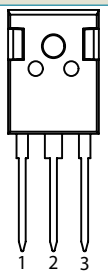
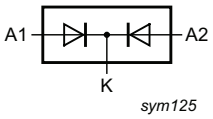
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values				Unit
Absolute maximum rating							
V_{RRM}	repetitive peak reverse voltage		650				V
$I_{O(AV)}$	limiting average output current	δ = 0.5 ; T_{mb} ≤ 129 °C; square-wave pulse; both diodes conducting; Fig. 1; Fig. 2; Fig. 3	16				A
T_j	junction temperature		175				°C
Symbol	**Parameter**	**Conditions**		**Min**	**Typ**	**Max**	**Unit**
Static characteristics							
V_F	forward voltage	I_F = 8 A; T_j = 25 °C; per diode; Fig. 5		-	1.5	1.7	V
		I_F = 8 A; T_j = 150 °C; per diode; Fig. 5		-	1.8	2.1	V
		I_F = 8 A; T_j = 175 °C; per diode; Fig. 5		-	1.95	2.25	V
Dynamic characteristics							
Q_r	recovered charge	I_F = 8 A; V_R = 400 V; dI_F/dt = 500 A/µs; T_j = 25 °C; per diode; Fig. 7		-	19	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode		 sym125
2	K	cathode		
3	A2	anode		
mb	K	mounting base; connected to cathode		

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC16650CW	TO247	WNSC16650CWQ	Tube	30	TO247N	20-Jul-2016

7. Marking

Table 4. Marking codes

Type number	Marking codes
WNSC16650CW	WNSC 16650CW

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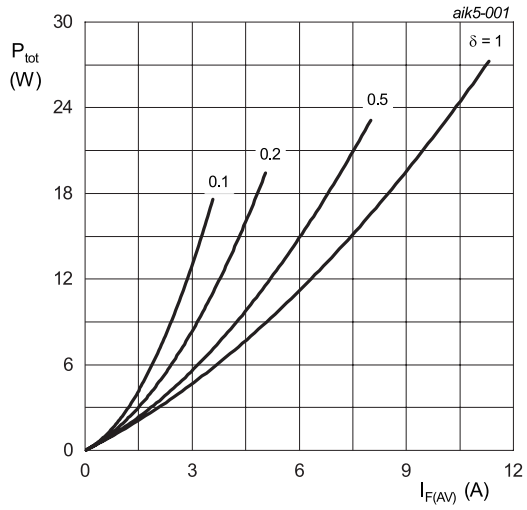
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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		650	V
V_{RWM}	crest working reverse voltage		650	V
V_R	reverse voltage	DC	650	V
I_{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25$ µs; $T_{mb} \leq 129$ °C; square-wave pulse; per diode	16	A
$I_{O(AV)}$	limiting average output current	$\delta = 0.5$; $T_{mb} \leq 129$ °C; square-wave pulse; both diodes conducting; Fig. 1; Fig. 2; Fig. 3	16	A
I_{FSM}	non-repetitive peak forward current	$t_p = 10$ ms; $T_{j(init)} = 25$ °C; sine-wave pulse; per diode	48	A
		$t_p = 10$ µs; $T_{j(init)} = 25$ °C; square-wave pulse; per diode	385	A
I^2t	I^2t for fusing	sine-wave pulse; $T_{j(init)} = 25$ °C; $t_p = 10$ ms; per diode	11.5	A^2s
T_{stg}	storage temperature		-55 to 175	°C
T_j	junction temperature		175	°C



$I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$

$V_o = 1.249$ V; $R_s = 0.1025$ Ω

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; typical values; per diode

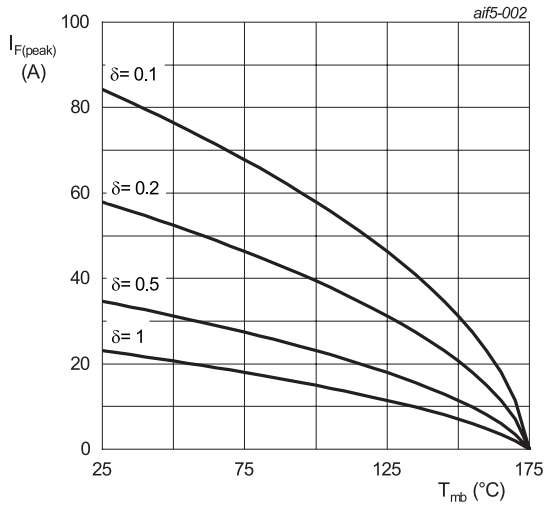


Fig. 2. Current derating as a function of mounting base temperature; per diode

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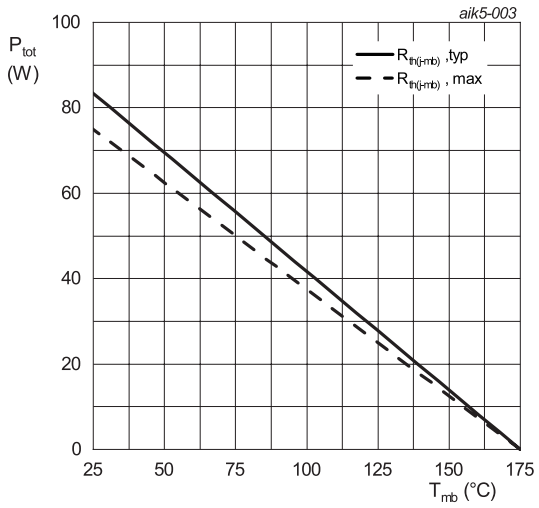


Fig. 3. Total power dissipation as a function of mounting base temperature; per diode

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	per diode; Fig. 4		-	1.8	2	K/W
		both diodes conducting		-	0.9	1	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	40	-	K/W

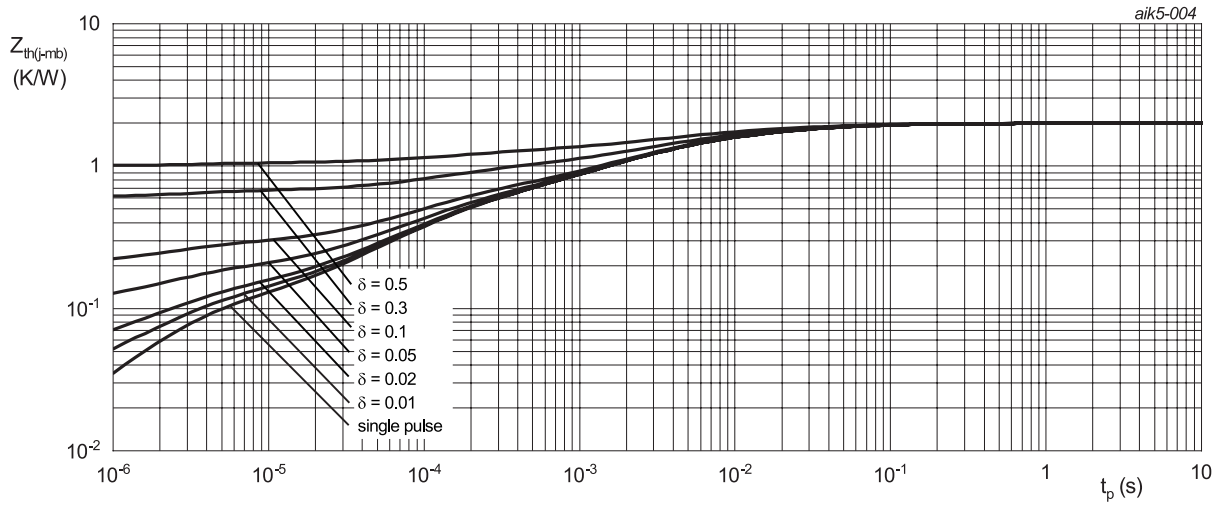


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

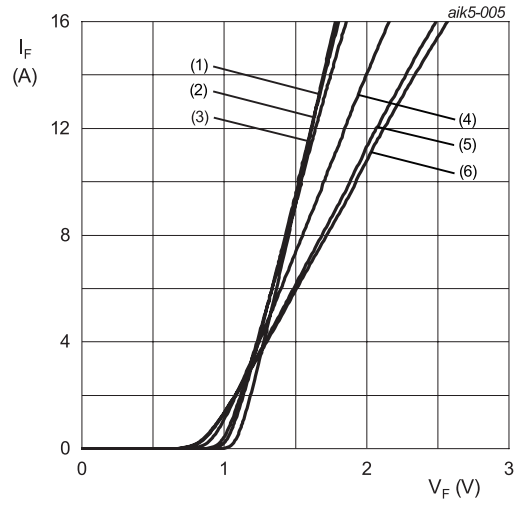
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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V_F	forward current	I_F = 8 A; T_j = 25 °C; per diode; Fig. 5		-	1.5	1.7	V
		I_F = 8 A; T_j = 150 °C; per diode; Fig. 5		-	1.8	2.1	V
		I_F = 8 A; T_j = 175 °C; per diode; Fig. 5		-	1.95	2.25	V
I_R	reverse current	V_R = 650 V; T_j = 25 °C; per diode; Fig. 6		-	-	50	µA
		V_R = 650 V; T_j = 175 °C; per diode; Fig. 6		-	-	200	µA
Dynamic characteristics							
Q_r	recovered charge	I_F = 8 A; V_R = 400 V; dI_F/dt = 500 A/µs; T_j = 25 °C; per diode; Fig. 7		-	19	-	nC
C_d	diode capacitance	f = 1 MHz; V_R = 1 V; T_j = 25 °C		-	250	-	pF
		f = 1 MHz; V_R = 300 V; T_j = 25 °C		-	31	-	pF
		f = 1 MHz; V_R = 600 V; T_j = 25 °C		-	28	-	pF
E_{as}	non-repetitive avalanche energy	I_R = 4.9 A; L = 5 mH; $T_{j(init)}$ = 25 °C		60	-	-	mJ



V_o = 1.249 V; R_s = 0.1025 Ω
(1) T_j = -55 °C; typical values
(2) T_j = 0 °C; typical values
(3) T_j = 25 °C; typical values
(4) T_j = 100 °C; typical values
(5) T_j = 150 °C; typical values
(6) T_j = 175 °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values; per diode

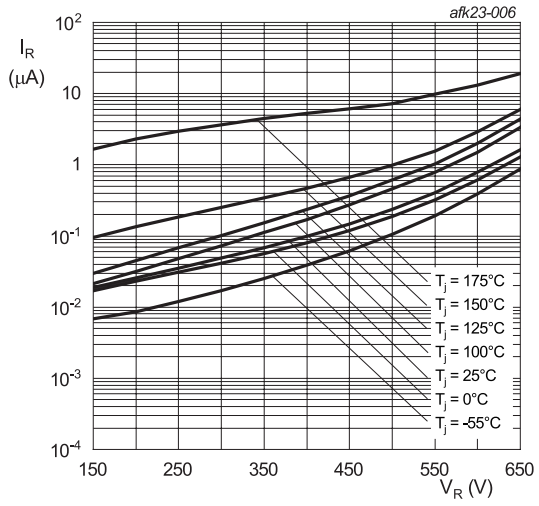


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value; per diode

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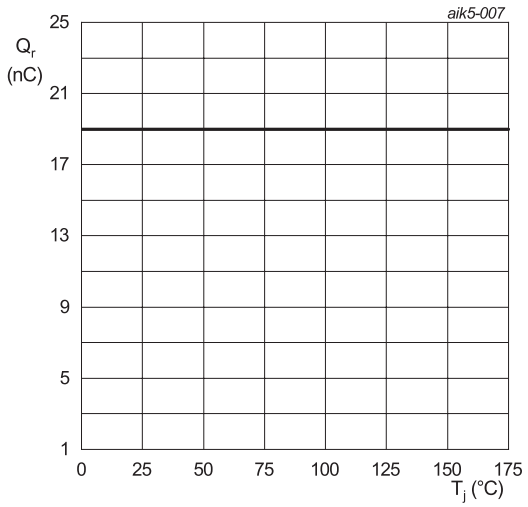


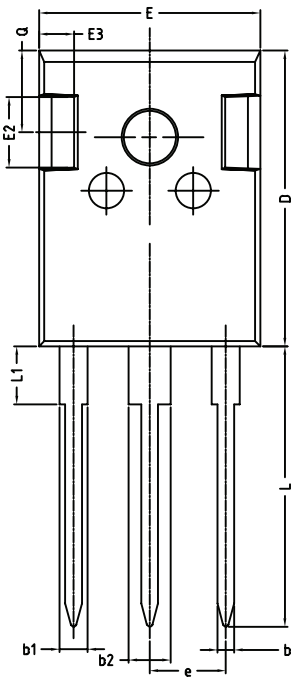
Fig. 7. Recovered charge as a function of junction temperature; per diode

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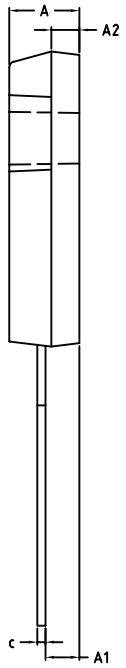
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11. Package outline

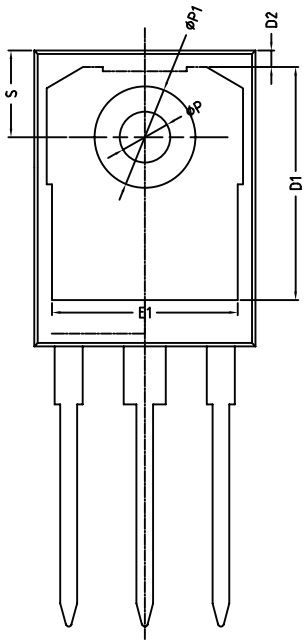
Plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3-lead TO-247 SOT429N



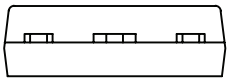
TOP VIEW



SIDE VIEW



BOTTOM VIEW



SIDE VIEW

UNIT		A	A1	A2	b	b1	b2	c	D	D1	D2	E	E1	E2	E3	e	L	L1	P	P1	Q	S
mm	MAX	5.20	2.60	2.10	1.40	2.20	3.20	0.70	21.10	16.85	1.35	15.90	13.50	5.20	2.60	5.45	20.10	4.75	3.70	7.40	6.00	6.25
	NOM																					
	MIN	4.70	2.20	1.90	1.00	1.80	2.80	0.50	20.90	16.25	1.05	15.70	13.10	4.80	2.40		19.80	–	3.50	–	5.60	6.05

OUTLINE VERSION	REFERENCES				PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT429N		TO-247				

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